

# ROITHNER LASERTECHNIK

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## RLT9830MG-N

## TECHNICAL DATA



### High Power Infrared Laserdiode

Structure: index guided, single transverse mode

Lasing wavelength: 980 nm typ.

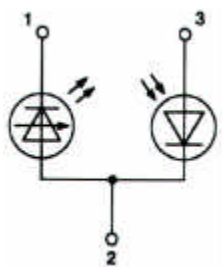
Output power: 30 mW cw

Package: 5.6 mm, TO-18

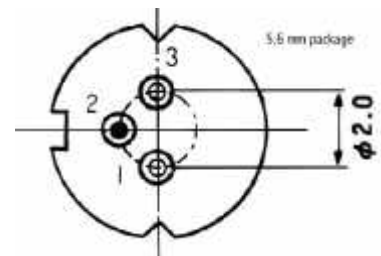


**NOTE!**  
LASERDIODE  
MUST BE COOLED!

#### PIN CONNECTION:



- 1) Laser diode cathode
- 2) Laser diode anode and photodiode cathode
- 3) Photodiode anode



#### Maximum Ratings (T<sub>c</sub> = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	P <sub>o</sub>	30	mW
LD Reverse Voltage	V <sub>R(LD)</sub>	2	V
PD Reverse Voltage	V <sub>R(PD)</sub>	30	V
Operation Case Temperature	T <sub>C</sub>	-10 .. +60	°C
Storage Temperature	T <sub>STG</sub>	-40 .. +85	°C

#### Optical-Electrical Characteristics (T<sub>c</sub> = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Threshold Current	I <sub>th</sub>	cw	10	15	20	mA
Operation Current	I <sub>op</sub>	P <sub>o</sub> = 30 mW		60	80	mA
Operating Voltage	V <sub>op</sub>	P <sub>o</sub> = 30 mW		1.5	1.7	V
Lasing Wavelength	λ <sub>p</sub>	P <sub>o</sub> = 30 mW	970	980	983	nm
Beam Divergence	θ <sub>  </sub>	P <sub>o</sub> = 30 mW	7	8	12	°
Beam Divergence	θ <sub>⊥</sub>	P <sub>o</sub> = 30 mW	30	33	38	°
Slope Efficiency	η	cw	0.5	0.7	1	mW/mA
Monitor Current	I <sub>m</sub>	P <sub>o</sub> = 30 mW		0.75	1	mA